

R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. These techniques are described in "[A Simple Method of Generating Thermal Models for a Power MOSFET](#)"[1]. When implemented in P-Spice, these values have matching characteristic curves to the Single Pulse Transient Thermal Impedance curves for the MOSFET.

R-C values for the electrical circuit in the Foster/Tank and Cauer/Filter configurations are included.

Note:

For a detailed explanation of implementing these values in P-SPICE, refer to [Application Note AN609 Thermal Simulations Of Power MOSFETs on P-SPICE Platform](#).

R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION			
Thermal Resistance (°C/W)			
Junction to	Ambient	Case	Foot
RT1	15.0539	N/A	26.1733
RT2	87.5420	N/A	32.9065
RT3	6.0259	N/A	9.7466
RT4	41.3782	N/A	6.1736
Thermal Capacitance (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	2.7488 m	N/A	48.6698 m
CT2	9.4137 m	N/A	10.5326 m
CT3	8.8327 m	N/A	7.4509 m
CT4	1.3399	N/A	3.7067 m

This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION**R-C VALUES FOR FILTER CONFIGURATION**

Thermal Resistance ($^{\circ}\text{C}/\text{W}$)			
Junction to	Ambient	Case	Foot
RF1	18.3376	N/A	10.7258
RF2	36.5492	N/A	13.6338
RF3	54.4923	N/A	18.6293
RF4	40.6209	N/A	32.0111
Thermal Capacitance (Joules/ $^{\circ}\text{C}$)			
Junction to	Ambient	Case	Foot
CF1	1.1511 m	N/A	1.7968 m
CF2	5.7897 m	N/A	1.0445 m
CF3	2.8122 m	N/A	4.1115 m
CF4	1.3222	N/A	15.8026 m

Note: NA indicates not applicable

Reference:

[1] "A Simple Method of Generating Thermal Models for a Power MOSFET" by Wharton McDaniel and Kandarp Pandya. IEEE / SEMITHERM 2002

